LA1835



Home Stereo Single-Chip Tuner IC with Electronic Tuning Support

Overview

The LA1835 is an AM, FM IF and MPX single-chip tuner IC that supports electronic tuning. It was developed specifically for use in home stereo products and is optimal for products with auto-seek systems, since it combines SD and IF counting in its auto-seek implementation. Furthermore, since the FM detector and MPX VCO circuits are adjustment free, adoption of the LA1835 can reduce the number of adjustment steps in the production line.

Functions

- AM: RF amplifier, mixer, oscillator (with ALC), IF amplifier, detector, AGC, oscillator buffer, tuning indicator (narrow-band SD), IF buffer output, stereo IF output
- FM IF: IF amplifier, quadrature detector, band muting, tuning indicator, IF buffer output, S-meter
- MPX: PLL stereo decoder, stereo indicator, forced mono, VCO stop function, adjacent channel interference rejection function (114 kHz), post-amplifier with muting function

Features

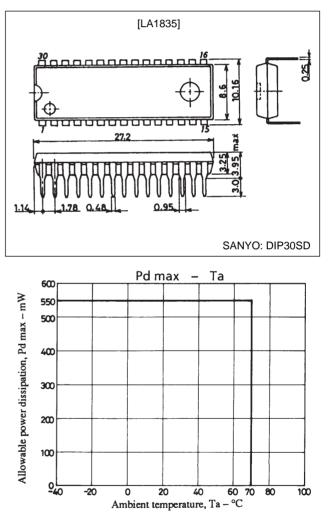
- Significant reduction in the number of manufacturing adjustment steps
 - FM detector: Adjustment free (using a ceramic discriminator)
 - MPX VCO: Adjustment free (using a ceramic resonator)
- Tuning indicator output provided. (This pin can also be used as a narrow band stop signal and as a muting drive output.)
- Adjustable FM stop sensitivity and bandwidth
- Built-in AM local oscillator buffer

- Support for AM low band cut control
- Adjustable AM stop sensitivity

Package Dimensions

unit: mm

3196-DIP30SD



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Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		9.0	V
Allowable power dissipation	Pd max	Ta ≤ 70°C	550	mA
Operating temperature	Topr		-20 to +70	°C
Storage temperature	Tstg		-40 to +125	°C

Operating Conditions at $Ta=25^{\circ}C$

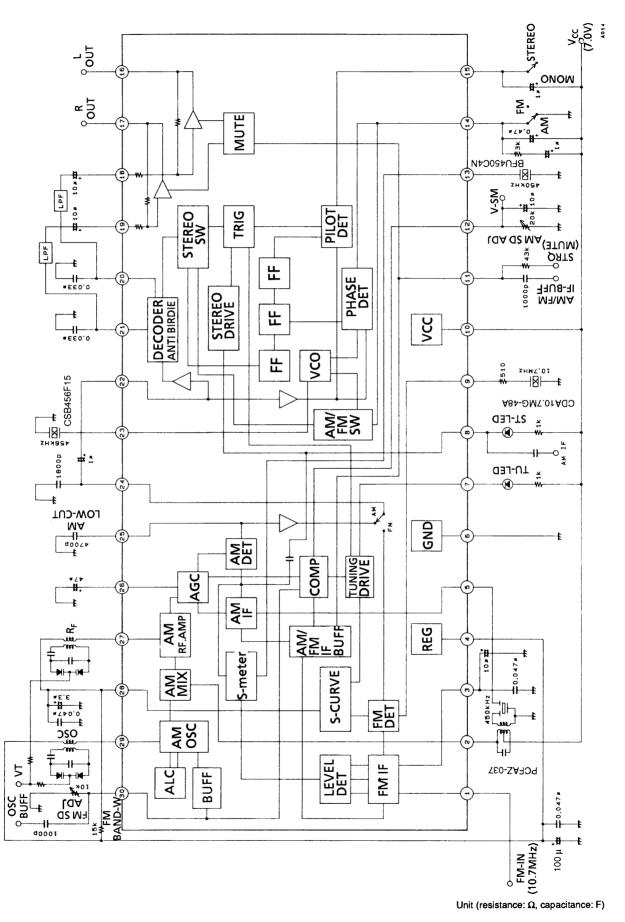
Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		7.0	V
Operating supply voltage	V _{CC} op		6.5 to 8.5	V

Operating Characteristics

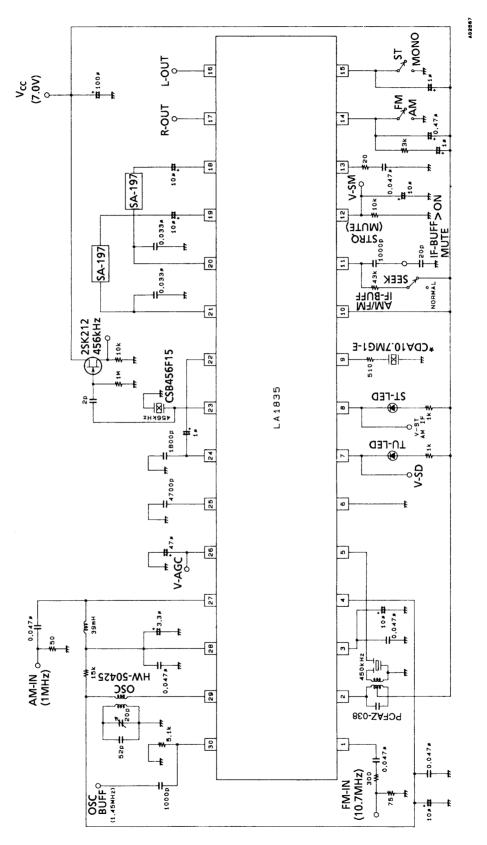
at Ta = 25°C, V_{CC} = 7.0 V, in the specified test circuit using the IC59-3004 socket (Yamaichi Electric Co., Ltd.)

Parameter	Symbol	Conditions	min	typ	max	Unit
[FM Characteristics (mono): fc = 1				96	max	0
Quiescent current	I _{CCO-FM}	No input	23	37	46	mA
Demodulator output	V _{O-FM}	100 dBµ, 100% modulation, the pin 16 output	665	1000	1330	mVrms
Channel balance (monaural)	C. B-momo	100 dBµ, 100% modulation, pin 16 output/pin 17 output	-1.5	0	+1.5	dB
Total harmonic distortion	THD-FM	100 dBµ, 100% modulation, the pin 16 output		0.3	1.5	%
Signal-to-noise ratio	S/N-FM	100 dBµ, 100% modulation, the pin 16 output	67	74		dB
AM suppression ratio	AMR	100 dBµ, 30% AM modulation, the pin 16 output	35	50		dB
Input limiting voltage	-3dBL.S	100 dBµ, referenced to 100%, with the input down 3 dB		27	35	dBµ
SD indicator sensitivity	SD-on-FM		47	57	67	dBµ
SD indicator bandwidth	SD- _{BW}	100 dBu	120	190	280	kHz
IF counter buffer output	V _{IF Buff-FM}	100 dBµ, the pin 11 output	80	120	160	mVrms
	V _{SM-FM} (1)	0 dBµ, the pin 12 output	0	0.3	1.0	V
S-meter output	V _{SM-FM} (2)		0.7	1.5	2.5	V
	V _{SM-FM} (3)	100 dBµ, the pin 12 output	2.5	4.0	5.0	V
Muting attenuation	Mute-Att	100 dBµ, 100% modulation, the pin 16 output	80	95		dB
•		= 1 kHz, L + R = 90%, pilot = 10%, V _{IN} = 100 dBµ]				42
Separation-left	Sep-L	Left channel modulated; pin 17 output/pin 16 output	30	45		dB
Separation-right	Sep-R	Right channel modulated; pin 16 output/pin 17 output	30	45		dB
Stereo on level	ST-on	The pilot modulation such that $V7 < 0.7 V$	1.8	3.6	6.0	%
Stereo off level	ST-off	The pilot modulation such that $V7 > 4.5 V$		2.5	0.0	%
Total harmonic distortion (main)	THD-main	The pin 16 output		0.3	1.5	%
Channel balance (main)	C. B-main	Pin 16 output/pin 17 output	-1.5	0	+1.5	dB
Capture range	C. R.	Pilot = 10%		±1.5		%
Adjacent channel rejection ratio	B. Rej	fs = 113 kHz, VS = 90%, pilot = 10%, the pin 16 output		40		dB
[AM Characteristics: fc = 1000 kH						
Quiescent current	I _{CCO-AM}	No input	21	29	42	mA
	V _{O-AM} (1)	23 dBµ, 30% modulation, the pin 16 output	25	45	90	mVrms
Detector output	V _{O-AM} (2)	80 dBµ, 30% modulation, the pin 16 output	195	310	490	mVrms
	S/N- _{AM} (1)	23 dBµ, 30% modulation, the pin 16 output	16	20		dB
Signal-to-noise ratio	S/N- _{AM} (2)	80 dBµ, 30% modulation, the pin 16 output	48	54		dB
	THD-AM (1)	80 dBµ, 30% modulation, the pin 16 output	-	0.3	1.0	%
Total harmonic distortion	THD-AM (2)	100 dBµ, 30% modulation, the pin 16 output		0.4	1.2	%
	THD-AM (3)	80 dBµ, 80% modulation, the pin 16 output		1.0	4.0	%
SD indicator sensitivity	SD-on-AM		20	30	40	dBµ
Local oscillator buffer output	V _{OSC-AM}	No input, the pin 30 output	110	160		mVrms
Low-band attenuation	Low-Cut	The output for fm = 100 Hz referenced to fm = 1 kHz	5.0	7.0	11.0	dB
IF counter buffer output	V _{IF Buff-AM}	80 dBµ, unmodulated signal, the pin 11 output	140	200	280	mVrms
Stereo IF output	V _{STIF-AM}	80 dBµ, unmodulated signal, the pin 8 output	8.0	17.0	24.0	mVrms
	V _{SM-AM} (1)	0 dBµ, unmodulated signal	0	0	0.2	V
S-meter output	V _{SM-AM} (2)		1.3	3.0	4.5	V
	SIVI-AIVI (-)	· · · · · ·				

Sample Application Circuit



Test Circuit Diagram



Unit (resistance: Ω , capacitance: F)

Note: Since an IC socket is used, these values differ from those used when the IC is mounted on a printed circuit board.

Pin Functions

No.	Function	Voltage	Internal equivalent circuit	Note
1	FM IF input	Vreg		Input impedance: ri = 330 Ω
2	AM mixer output	V _{CC}	2 	Recommended AM IFT coil: PCFAZ-037 (Toko Co., Ltd.)
3	FM IF input bypass	Vreg		Also used for the AF noise filter.
4	REG	Vreg	AD 1488	Vreg = 3.6 V
5	AM IF input	Vreg	5 5 8 01489	Input impedance: ri = 2 kΩ
6	GND	0		
7 8	Tu-LED ST-LED Also functions as the AM IF output.	V _{CC} V _{CC}		Active low open collector outputs Pin 8 is used for the AM stereo IF output.
9	FM detector	2.1 (FM) 2.7 (AM)		Recommended ceramic discriminator: CDA 10.7MG-48 (Murata Mfg. Co., Ltd.)

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No.	Function	Voltage	Internal equivalent circuit	Note
10	V _{CC}	V _{CC}		
11	AM/FM IF buffer output Also functions as the output control switch (muting switch).	0		A voltage of 1.3 V or higher turns on the post- amplifier output muting. A voltage of 4.0 V or higher turns on the IF buffer output. The recommended control voltage for turning muting on is 1.9 V.
12	S-meter output Also functions as the AM SD sensitivity adjustment.	0.3 (FM) 0 (AM)		The AM SD sensitivity can be adjusted with the resistor inserted between this pin and ground. Since the FM SD sensitivity is affected by this resistor, the AM SD sensitivity must be adjusted first.
13	AM narrow band ceramic filter connection	1.5	13 A01494	Recommended narrow band ceramic filter: BFU450 C4N (Murata Mfg. Co., Ltd.)
14	Phase comparator low- pass filter (FM/AM switch)	V _{CC} – 1.4 (FM) 0 (AM)		The LA1835 switches to AM mode when this pin is connected to ground.
15	Pilot detector low-pass filter (forced mono) (VCO stop)	V _{CC} – 1.0	A01496	If a current of 50 μA or larger flows from this pin, the LA1835 switches to mono mode. The VCO is stopped if this pin is connected to ground.
16 17	Post-amplifier left and right outputs	Vreg Vreg	-K -K -(17) A01497	Output impedance: ro = 200 Ω Pin 16: left output Pin 17: right output
18 19	Post-amplifier left and right inputs	Vreg Vreg	(19) ((19) A01498	Inverting inputs, ri = 3.3 kΩ Pin 18: left input Pin 19: right input

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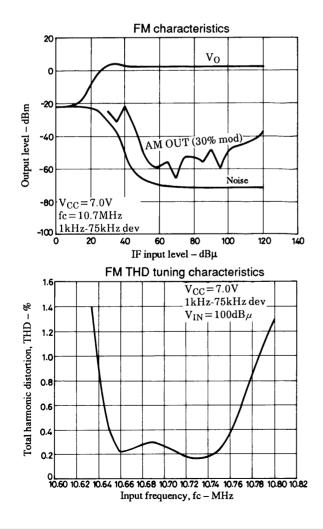
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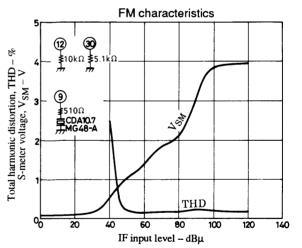
No.	Function	Voltage	Internal equivalent circuit	Note
110.		vollage		INOLE
20 21	MPX outputs Left and right outputs	3.5 3.5	20 ₹ ((21)) ∧01499	Output impedance ro = 3.3 kΩ Pin 20: left de-emphasis Pin 21: right de-emphasis
22	MPX input	2.9	22 K A01500	Input impedance $ri = 20 k\Omega$ Increasing the value of the external capacitor connected between this pin and pin 24 improves the low frequency separation characteristics. However, the impulse noise associated with switching between AM and FM also increases.
23	MPX VCO	3.5 (FM) 0 (AM)	23 4 4 4 401501	Recommended ceramic oscillator: CSB456F15 (Murata Mfg. Co., Ltd.)
24	AM/FM demodulator output	2.9 (FM) 3.0 (AM)		Output impedances FM: ro = 250 Ω AM: ro = 10 k Ω The separation can be adjusted by changing the value of the external capacitor connected between this pin and ground.
25	AM low cut	2.9 (FM) 3.0 (AM)		The low-band frequency characteristics of the AF demodulator can be adjusted by changing the value of the external capacitor connected between this pin and ground. The AM detector output can be attenuated by adding a resistor in series with the capacitor.
26	AMAGC	0 (FM) 0.5 (AM)	-1 26 A01504	The internal load resistance, R is 6.7 k Ω .
27	AM RF input	Vreg	(27) K	Pin 27 must be used at the same voltage as pin 4, the regulator voltage.

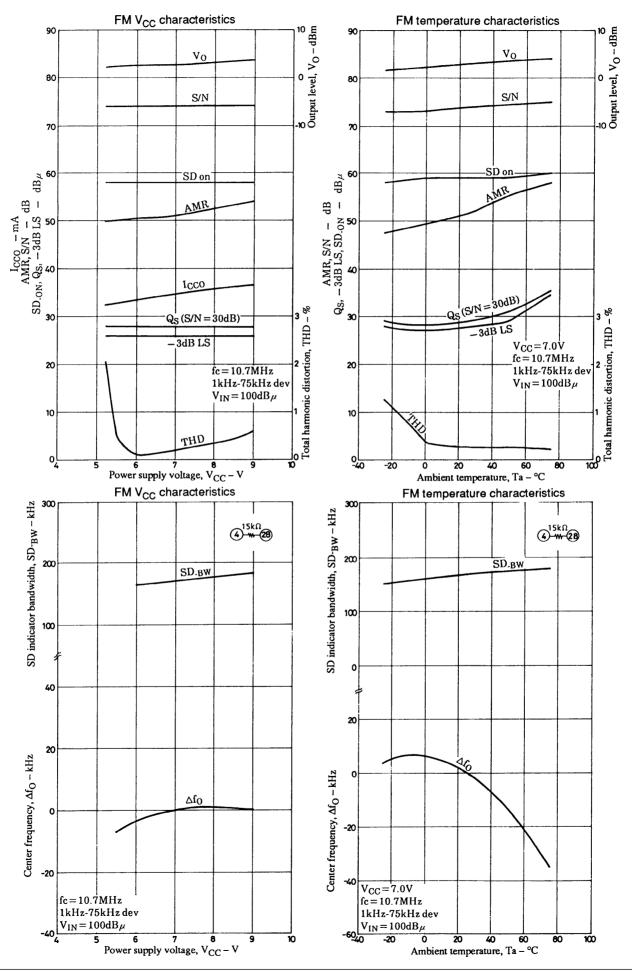
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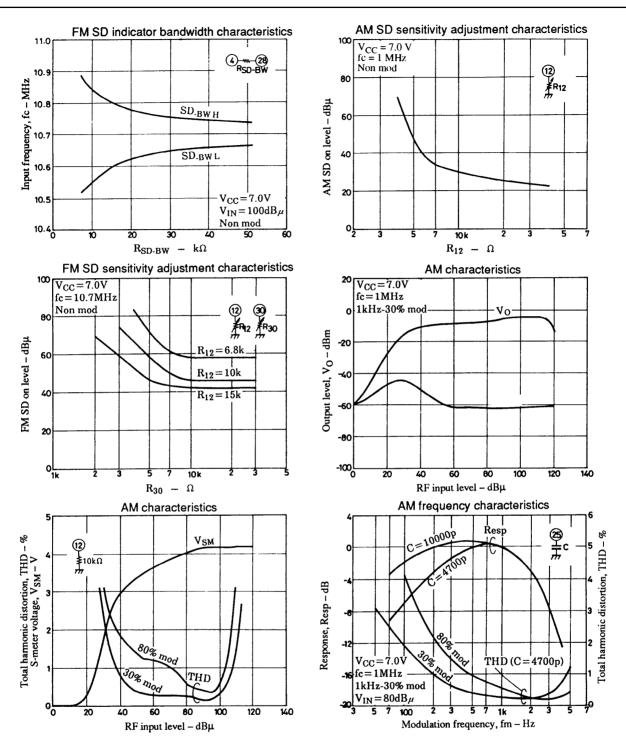
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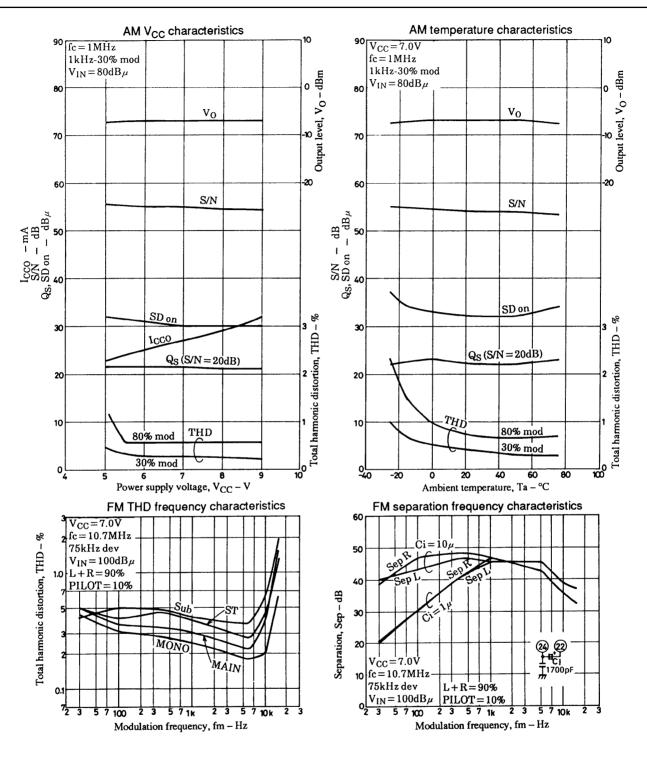
No.	Function	Voltage	Internal equivalent circuit	Note
28	AFC	Vreg	28 A01506	The FM SD bandwidth can be adjusted by changing the value of the external resistor inserted between pin 28 and pin 4, the regulator voltage.
29	OSC	Vreg	29 401507	The oscillator coil is connected between pin 29 and pin 4, the regulator voltage.
30	Oscillator buffer output Also functions as the FM SD sensitivity adjustment.	1.6 (FM) 1.3 (AM)		The FM SD sensitivity can be adjusted by changing the value of the external resistor inserted between this pin and ground. The AM SD sensitivity must be adjusted before the AM FD sensitivity. Output impedance ro = 200Ω

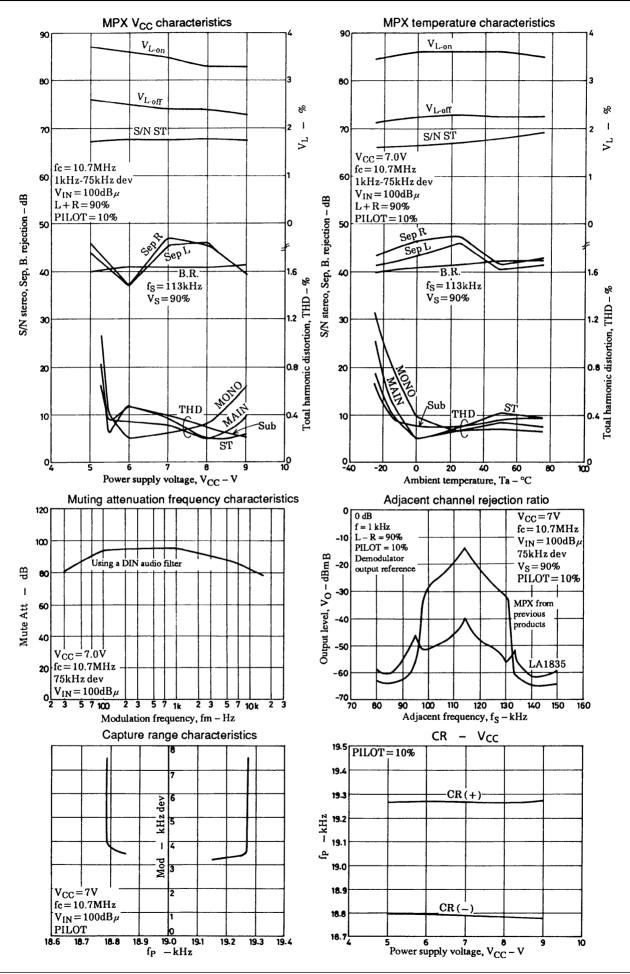


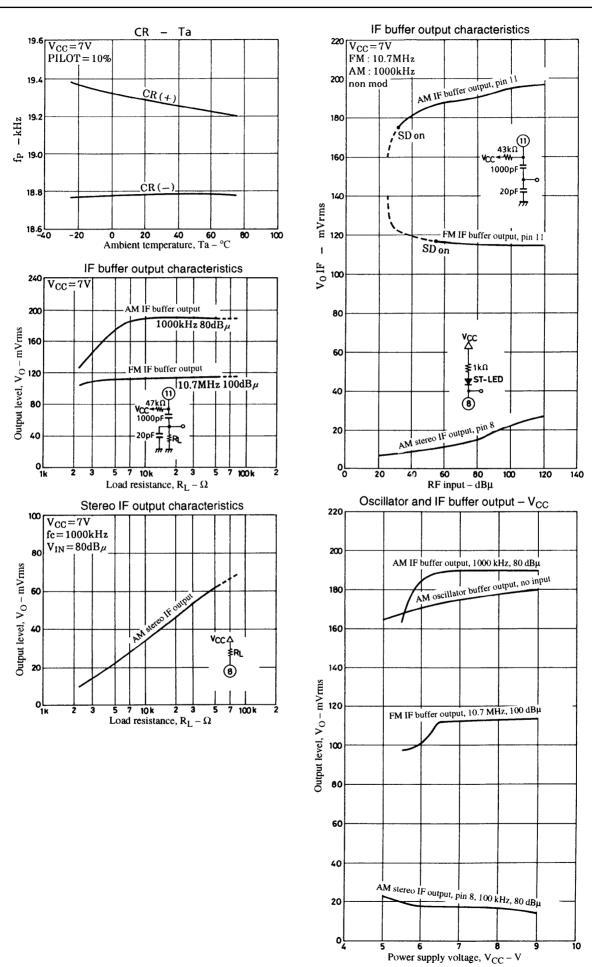


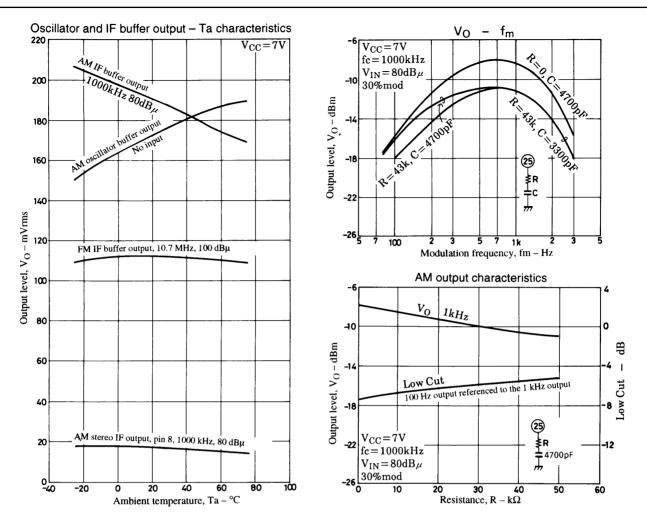












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